TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WZ14FU,TC7WZ14FK

Triple Schmitt Inverter

Features

High output drive : ±24 mA (min) at V_{CC} = 3 V

Super high speed operation : t_{pd} = 3.7 ns (typ.)

at $V_{CC} = 5 \text{ V}$, 50 pF

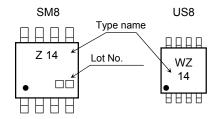
• Operation voltage range : V_{CC (opr)} = 1.65~5.5 V

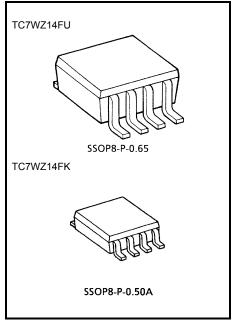
• 5.5-V tolerant inputs

• 5.5-V power down protection outputs

- Matches the performance of TC74LCX series when operated at 3.3-V $\mbox{V}_{\mbox{CC}}$

Marking





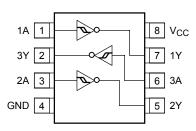
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	-0.5~6	V
Input diode current	lık	-20	mA
Output diode current	lok	-20	mA
DC output current	I _{OUT}	±50	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	300 (SM8) 200 (US8)	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10 s)	TL	260	°C

Pin Assignment (top view)





Logic Diagram



Truth Table

INPUT	OUTPUT				
А	Y				
L	Н				
Н	L				

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	1.65~5.5	V
	VCC	1.5~5.5 (Note 1)	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	\/a=	0~5.5 (Note 2)	V
	Vout	0~ V _{CC} (Note 3)	V
Operating temperature	T _{opr}	-40~85	°C

Note 1 : Data retention only

Note 2 : $V_{CC} = 0 V$

Note 3: High or low state



Electrical Characteristics

Characteristics Symbol		Symbol	ol Test Condition			Ta = 25°C		Ta = -40~85°C		Unit	
		1630	rest Condition		Min	Тур.	Max	Min	Max	Offic	
High-level				1.65	0.6	1.0	1.4	0.6	1.4		
				1.8	0.7	1.1	1.5	0.7	1.5		
	V _P	_		2.3	1.0	1.4	1.8	1.0	1.8		
				3.0	1.3	1.75	2.2	1.3	2.2		
					4.5	1.9	2.45	3.1	1.9	3.1	
Threshold					5.5	2.2	2.9	3.6	2.2	3.6	
voltage					1.65	0.2	0.5	0.8	0.2	0.8	
					1.8	0.25	0.55	0.9	0.25	0.9	
	I am land	.,			2.3	0.4	0.75	1.15	0.4	1.15	V
	Low-level	V _N		_		0.6	1.0	1.5	0.6	1.5	v
					4.5	1.0	1.43	2.0	1.0	2.0	
					5.5	1.2	1.7	2.4	1.2	2.4	
					1.65	0.1	0.48	0.9	0.1	0.9	
					1.8	0.15	0.54	1.0	0.15	1.0	
Lhustavasia u	alta a a	\/			2.3	0.25	0.65	1.1	0.25	1.1	
Hysteresis v	oitage	VH		_	3.0	0.4	0.77	1.2	0.4	1.2	
			-	4.5	0.6	1.01	1.5	0.6	1.5		
					5.5	0.7	1.18	1.7	0.7	1.7	
					1.65	1.55	1.65	_	1.55	_	
				$I_{OH} = -100\mu A$	2.3	2.2	2.3	_	2.2	_	
					3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
High-level or	utput voltage	VOH VIN	$V_{IN} = V_{IL}$	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52		1.29	_	
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.14	_	1.9	_	
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.75		2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.62	_	2.3	_	
				$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.13		3.8	_	V
				I _{OH} = 100 μA	1.65	_	0	0.1		0.1	v
					2.3	_	0	0.1	—	0.1	
					3.0	_	0	0.1	_	0.1	
Low-level output voltage				4.5	_	0	0.1	_	0.1		
	VoL	$V_{IN} = V_{IH} \\$	I _{OH} = 4 mA	1.65		0.08	0.24		0.24		
			I _{OH} = 8 mA	2.3		0.1	0.3		0.3		
		I _{OH} = 6 mA	3.0	_	0.16	0.4		0.4			
			I _{OH} = 24 mA	3.0		0.24	0.55		0.55		
				$I_{OH} = 32 \text{ mA}$	4.5		0.25	0.55		0.55	
Input leakage	e current	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5		_	±1		±10	μΑ
Power off lea	akage current	l _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0.0	_	_	1	_	10	μΑ
Quiescent su	ipply current	Icc	V _{IN} = 5.5 V or GND		1.65~5.5	_	_	1	_	10	μΑ

AC Characteristics (input: $t_r = t_f = 3$ ns)

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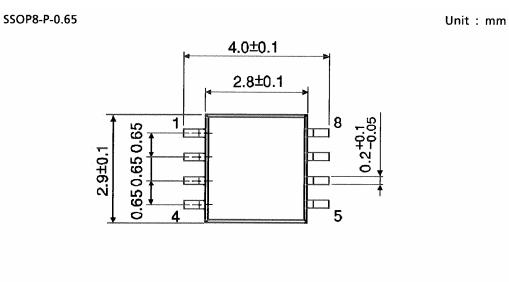
Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	^t pLH ^t pHL	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	1.8 ± 0.15	2.0	9.1	15.0	2.0	15.6	- ns
			2.5 ± 0.2	1.0	5.0	9.0	1.0	9.5	
			3.3 ± 0.3	1.0	3.7	6.3	1.0	6.5	
			5.0 ± 0.5	0.5	3.1	5.2	0.5	5.5	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	3.3 ± 0.3	1.5	4.4	7.2	1.5	7.5	
			5.0 ± 0.5	0.8	3.7	5.9	0.8	6.2	
Input capacitance	C _{IN}	_	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	C	(Note 4)	3.3	_	33		_	_	pF
	C _{PD}		5.5	_	43		_	_	

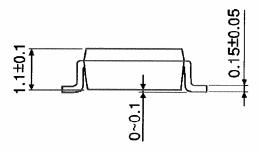
Note 4: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$$

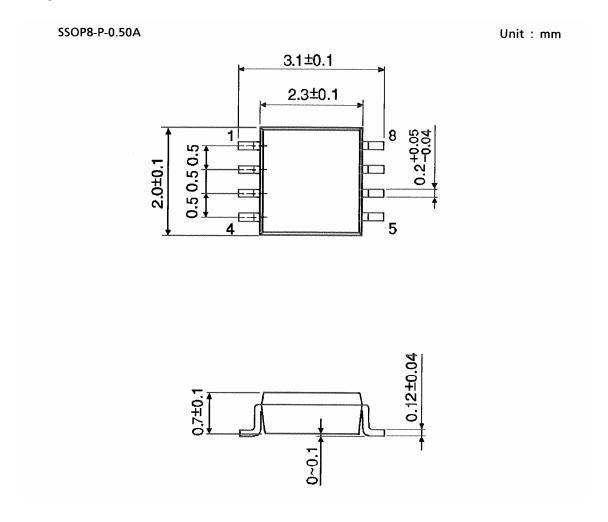
Package Dimensions





Weight: 0.02 g (typ.)

Package Dimensions



Weight: 0.01 g (typ.)

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